

SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGY:: PUTTUR (AUTONOMOUS)

B.Tech I Year II Semester Regular Examinations October-2020 BASIC ELECTRICAL AND ELECTRONICS ENGINEERING

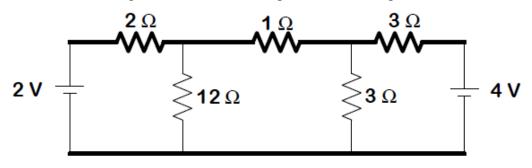
(Common to CSE, CSIT & AGE)

Time: 3 hours Max. Marks: 60

(Answer all Five Units $6 \times 10 = 60$ Marks)

PART - A
UNIT-I

1 Find the current through 12Ω resistor for the given circuit using Kirchoff's laws. 10M



OR

2 a State and explain Ohm's law

5M

b Explain in detail about Passive elements

5M

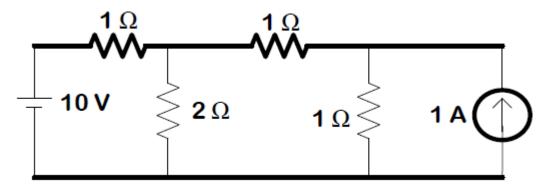
UNIT-II

3 a State superposition theorem.

3M

b Calculate the current in the 20Ω resistor in the given circuit using superposition theorem.

7M





4 Find the short circuit parameters for the given circuit **10M** UNIT-III **a** Derive torque equation of a D.C motor. 5 **5M b** A 6-pole lap wound shunt motor has 500 conductors, the armature and shunt field **5M** resistances are 0.05Ω and 25Ω respectively. Find the speed of the motor if it takes 120A from dc supply of 100V, flux per pole is 20mWb. a Derive the condition for maximum efficiency of the transformer. 6 **5M** Discuss about the voltage regulation of the transformer. **5M UNIT-IV** 7 Explain the behavior of PN junction diode. **5M** Derive the expression for ripple factor and Efficiency of Half wave rectifier. b 5M 8 Write notes on diode specifications and Diode Applications. **6M** Discuss the operation of full wave rectifier with capacitor filter. **4M** b **UNIT-V** Discuss the operation of PNP transistor with diagram. 9 **5M** Explain the characteristics of CE configuration. **5M a** A transistor operating in CB configuration has $I_C = 2.98$ mA, $I_E = 3.00$ mA and I_{CO} 10 **5M** =0.01 mA. What current will flow in the collector circuit for this transistor when connected in CE configuration with a base current of 30µA? **b** Describe the Voltage Divider Bias Network of BJT with diagram and equations **5M UNIT-VI** Explain the construction and principle of operation of N-channel JFET. 11 **5M** Define the JFET Volt-Ampere Characteristics and determine FET parameters. **5M** OR **12** a Draw the construction of EMOSFET and explain its operation. **5M** Write the comparisons for BJT and JFET. **5M**

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